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Littelfuse® Expertise Applied | Answers Delivered

Sx02xS Series





Main Features

| Symbol | Value | Unit |
|------------------------------------|------------|------|
| I _{T(RMS)} | 1.5 | А |
| V _{DRM} /V _{RRM} | 400 to 600 | V |
| I _{GT} | 200 | μА |

Applications

The Sx02xS EV series is specifically designed for Gas Ignition applications that require high pulse surge current capability.

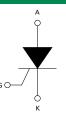
Description

New 1.5 Amp sensitive gate SCR series offers high static dv/dt with low turn off time (tq) through small die planar construction design. All SCR's junctions are glasspassivated to ensure long term reliability and parametric stability.

Features

- RoHS compliant and Halogen-Free
- Thru hole and surface mount packages
- Surge capability > 15Amps
- Blocking voltage (V_{DRM}/V_{RRM}) capability — up to 600V
- High dv/dt noise immunity
- Improved turn-off time (tq) < 35 µsec.
- Sensitive gate for direct microprocessor interface

Schematic Symbol



Absolute Maximum Ratings

| Symbol | Parameter | | Value | Unit | |
|---------------------|---|------------------------|---------------------------------|------|------------------|
| _ | RMS on-state current | TO-92 | $T_{c} = 65^{\circ}C$ | 1.5 | А |
| I _{T(RMS)} | (full sine wave) | SOT-223 | T _L = 95°C | 1.5 | |
| 1 | Average on-state current | TO-92 | $T_{\rm C} = 65^{\circ}{\rm C}$ | 0.95 | A |
| I _{T(AV)} | Average on-state current | SOT-223 | $T_{\rm C} = 95^{\circ}{\rm C}$ | 0.95 | |
| | Non repetitive surge peak on-state current | TO-92 | F = 50 Hz | 12.5 | A |
| I _{TSM} | (Single cycle, T _J initial = 25°C) | SOT-223 | F = 60 Hz | 15.0 | A |
| l²t | I²t Value for fusing | $t_p = 10 \text{ ms}$ | F = 50 Hz | 0.78 | A ² s |
| | i t value for fushing | $t_p = 8.3 \text{ms}$ | F = 60 Hz | 0.93 | A 5 |
| di/dt | Critical rate of rise of on-state current IG = 10mA | TO-92 SOT-223 | T _J = 125°C | 50 | A/µs |
| I _{GM} | Peak gate current $t_p = 10 \mu s$ $T_J = 125^{\circ}C$ | | | 1.0 | А |
| P _{G(AV)} | Average gate power dissipation $T_J = 125^{\circ}C$ | | | 0.1 | W |
| T _{stg} | Storage junction temperature range | -40 to 150 | °C | | |
| T _J | Operating junction temperature range | -40 to 125 | °C | | |

Teccor® brand Thyristors EV Series 1.5 Amp Sensitive SCRs

Electrical Characteristics (T₁ = 25°C, unless otherwise specified)

| Constant | Description | Test Conditions Sxt | | 2xS | I I with |
|-------------------|---|---|-----|-----|----------|
| Symbol | Description | lest Conditions | Min | Max | Unit |
| I _{GT} | DC Gate Trigger Current | $V_{D} = 12V; R_{L} = 60 \Omega$ | 15 | 200 | μΑ |
| V_{GT} | DC Gate Trigger Voltage | $V_D = 12V; R_L = 60 \Omega$ | _ | 0.8 | V |
| V _{GRM} | Peak Reverse Gate Voltage | $I_{RG} = 10 \mu A$ | 5 | _ | V |
| I _H | Holding Current | $R_{GK} = 1 k\Omega$ | _ | 5 | mA |
| (dv/dt)s | Critical Rate-of-Rise of Off-State Voltage | $T_{J} = 125^{\circ}\text{C}$ $V_{D} = V_{DRM} / V_{RRM}$ Exponential Waveform $R_{GK} = 1 \text{ k}\Omega$ | 25 | _ | V/µs |
| t _q | Turn-Off Time | $T_J = 125^{\circ}C @ 600 V$ $R_{GK} = 1 k\Omega$ | _ | 35 | μs |
| t _{gt} | Turn-On Time | $I_{\rm G} = 10$ mA PW = 15 μ sec $I_{\rm T} = 3.0$ A (pk) | _ | 3 | μs |

Static Characteristics (T_j = 25°C, unless otherwise specified)

| Symbol | Description | Test Conditions | Val | lue | Unit |
|------------------|------------------------------------|---|-----|------|------|
| Symbol | Description | rest Conditions | Min | Max | Onit |
| V _{TM} | Peak On-State Voltage | I _{TM} = 3.0A (pk) | _ | 1.70 | V |
| | Off-State Current, Peak Repetitive | $T_J = 25^{\circ}\text{C} @V_D = V_{DRM}$ $R_{GK} = 1 \text{ k}\Omega$ | _ | 5 | μΑ |
| I _{DRM} | On-State Current, Feak nepetitive | $T_{J} = 125^{\circ}\text{C } @ V_{D} = V_{DRM}$ $R_{GK} = 1 \text{ k}\Omega$ | _ | 500 | μΑ |

Thermal Resistances

| Symbol | Parameter | | | Value | Unit |
|---------------------|-----------------------|----------------------------|---------|-------|------|
| D | lunation to acce (AC) | 1 E A 1 | TO-92 | 50 | °C/W |
| $R_{\theta(J-C)}$ | Junction to case (AC) | $_{T} = 1.5A_{(RMS)}^{1}$ | SOT-223 | 25 | C/VV |
| D | Junction to ambient | I — 1 5 A 1 | TO-92 | 160 | °C/W |
| Π _{θ(J-A)} | Junction to ambient | $I_{T} = 1.5A_{(RMS)}^{1}$ | SOT-223 | 60 | C/VV |

¹ 60Hz AC resistive load condition, 100% conduction.

Additional Information







Figure 1: Normalized DC Gate Trigger Current vs. Junction Temperature

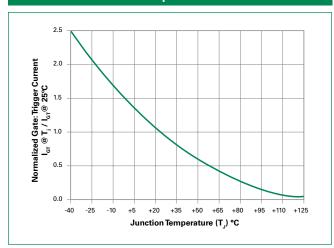


Figure 3: Normalized DC Gate Trigger Voltage vs. Junction Temperature

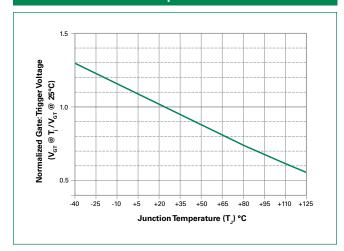
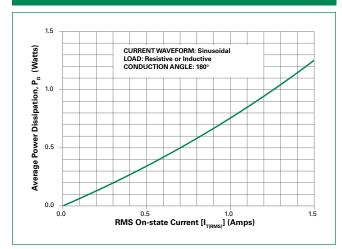


Figure 5: Power Dissipation (Typical) vs. RMS On-State Current



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Figure 2: Normalized DC Holding Current vs. Junction Temperature

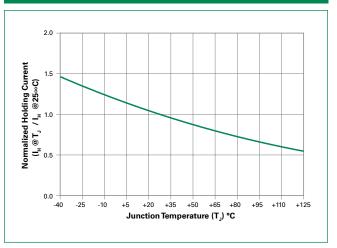


Figure 4: On-State Current vs. On-State Voltage (Typical)

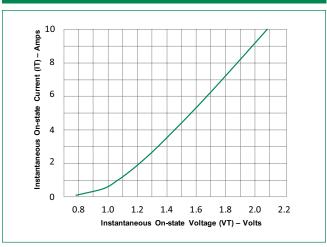
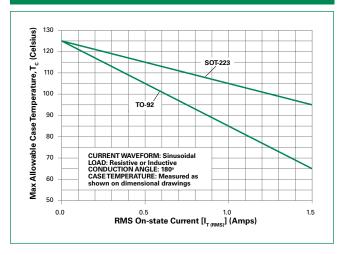
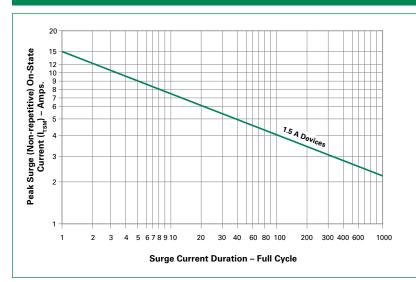


Figure 6: Maximum Allowable Case Temperature vs. On-State Current



Teccor® brand Thyristors EV Series 1.5 Amp Sensitive SCRs

Figure 7: Surge Peak On-State Current vs. Number of Cycles



Supply Frequency: 60Hz Sinusoidal Load: Resistive RMS On-State Current [I_{TIRMS}]: Max Rated Value at Specific Case Temperature

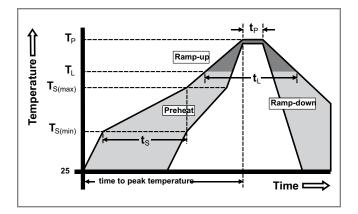
Notes:

- Gate control may be lost during and immediately
- following surge current interval.

 2. Overload may not be repeated until junction temperature has returned to steady-state rated value.

Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|-------------------------|
| | -Temperature Min (T _{s(min)}) | 150°C |
| Pre Heat | -Temperature Max (T _{s(max)}) | 200°C |
| | -Time (min to max) (t _s) | 60 – 180 secs |
| Average ramp up rate (Liquidus Temp) (T _L) to peak | | 5°C/second max |
| T _{S(max)} to T _L - Ramp-up Rate | | 5°C/second max |
| Reflow | -Temperature (T _L) (Liquidus) | 217°C |
| nellow | -Time (min to max) (t _s) | 60 – 150 seconds |
| PeakTemp | perature (T _P) | 260+ ^{0/-5} °C |
| Time within 5°C of actual peak Temperature (t _p) | | 20 - 40 seconds |
| Ramp-down Rate | | 5°C/second max |
| Time 25°C to peak Temperature (T _P) | | 8 minutes Max. |
| Do not exc | ceed | 280°C |





Physical Specifications

| Terminal Finish | 100% Matte Tin-plated. |
|-----------------|--|
| Body Material | UL recognized epoxy meeting flammability classification 94V-0. |
| Lead Material | Copper Alloy |

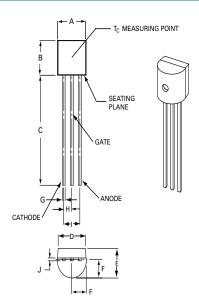
Design Considerations

Careful selection of the correct device for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the device rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

Environmental Specifications

| Test | Specifications and Conditions |
|---------------------------|---|
| AC Blocking | MIL-STD-750, M-1040, Cond A Applied Peak AC voltage @ 125°C for 1008 hours |
| Temperature Cycling | MIL-STD-750, M-1051, 100 cycles; -40°C to +150°C; 15-min dwell-time |
| Temperature/ Humidity | EIA / JEDEC, JESD22-A101 1008 hours; 320V - DC: 85°C; 85% rel humidity |
| High Temp Storage | MIL-STD-750, M-1031, 1008 hours; 150°C |
| Low-Temp Storage | 1008 hours; -40°C |
| Resistance to Solder Heat | MIL-STD-750 Method 2031 |
| Solderability | ANSI/J-STD-002, category 3, Test A |
| Lead Bend | MIL-STD-750, M-2036 Cond E |

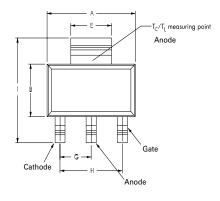
Dimensions — TO-92 (E Package)



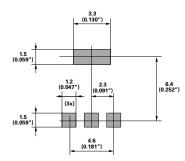
| Dimensions | Inc | Inches | | neters |
|------------|-------|--------|--------|--------|
| Dimensions | Min | Max | Min | Max |
| А | 0.175 | 0.205 | 4.450 | 5.200 |
| В | 0.170 | 0.210 | 4.320 | 5.330 |
| С | 0.500 | _ | 12.700 | _ |
| D | 0.135 | _ | 3.430 | _ |
| Е | 0.125 | 0.165 | 3.180 | 4.190 |
| F | 0.080 | 0.105 | 2.040 | 2.660 |
| G | 0.016 | 0.021 | 0.407 | 0.533 |
| Н | 0.045 | 0.055 | 1.150 | 1.390 |
| 1 | 0.095 | 0.105 | 2.420 | 2.660 |
| J | 0.015 | 0.020 | 0.380 | 0.500 |



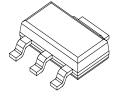
Dimensions - SOT-223



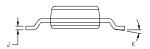
Pad Layout for SOT-223



Dimensions in Millimeters (Inches)







| D: | | Inches | | IV | lillimete | rs |
|------------|---------|--------|-------|------|-----------|------|
| Dimensions | Min | Тур | Max | Min | Тур | Max |
| А | 0.248 | 0.256 | 0.264 | 6.30 | 6.50 | 6.70 |
| В | 0.130 | 0.138 | 0.146 | 3.30 | 3.50 | 3.70 |
| С | _ | _ | 0.071 | _ | _ | 1.80 |
| D | 0.001 | _ | 0.004 | 0.02 | _ | 0.10 |
| Е | 0.114 | 0.118 | 0.124 | 2.90 | 3.00 | 3.15 |
| F | 0.024 | 0.027 | 0.034 | 0.60 | 0.70 | 0.85 |
| G | _ | 0.090 | _ | _ | 2.30 | _ |
| Н | _ | 0.181 | _ | _ | 4.60 | _ |
| I | 0.264 | 0.276 | 0.287 | 6.70 | 7.00 | 7.30 |
| J | 0.009 | 0.010 | 0.014 | 0.24 | 0.26 | 0.35 |
| K | 10° MAX | | | | | |

Product Selector

| Part Number | Volt | age | Cata Canaitivity | Dookowa |
|-------------|------|------|------------------|---------|
| ran Number | 400V | 600V | Gate Sensitivity | Package |
| S402ES | X | _ | 200μΑ | TO-92 |
| S602ES | _ | X | 200μΑ | TO-92 |
| S402TS | X | _ | 200μΑ | SOT-223 |
| S602TS | _ | X | 200μΑ | SOT-223 |

Packing Options

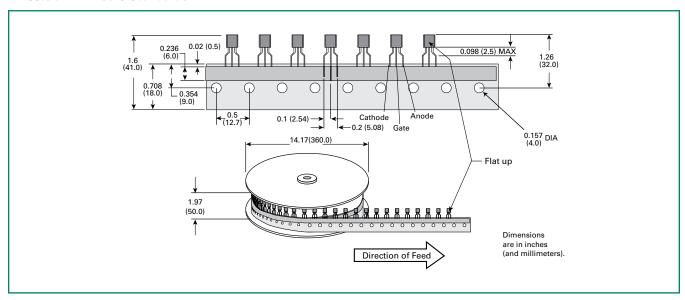
| Part Number | Marking | Weight | Packing Mode | Base Quantity |
|-------------|---------|---------|--------------|---------------|
| Sx02ES | Sx02ES | 0.217 g | Bulk | 2500 |
| Sx02ESAP | Sx02ES | 0.217 g | Ammo Pack | 2000 |
| Sx02ESRP | Sx02ES | 0.217 g | Tape & Reel | 2000 |
| Sx02TSRP | Sx02TS | 0.120 g | Tape & Reel | 1000 |

Note: x = voltage



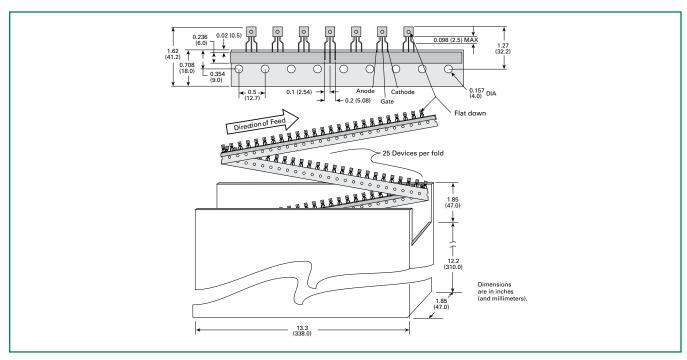
TO-92 (3-lead) Reel Pack (RP) Radial Leaded Specifications

Meets all EIA-468-C Standards



TO-92 (3-lead) Ammo Pack (AP) Radial Leaded Specifications

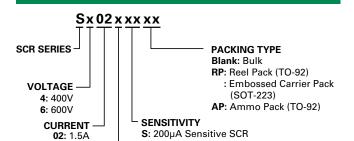
Meets all EIA-468-C Standards



Part Numbering System

Teccor® brand Thyristors EV Series 1.5 Amp Sensitive SCRs

SOT-223 Reel Pack (RP) Specifications 1.75 mm \oplus \oplus \oplus (III) \oplus \oplus \oplus \oplus **(** \oplus 5.5 mm 12 mm 180 mn 13 mm Abor Hole Diameter 13.4 mm



PACKAGE TYPE

E: TO-92

T: SOT-223

Part Marking System

